NSN 5961-01-380-2192

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-380-2192 **Inclosure Material:** Metal **Overall Length:** 133.72 millimeters **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 26.67 millimeters and 26.92 millimeters **Thread Size:** 0.378 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 600.0 repetitive peak reverse voltage and 720.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 150.00 amperes forward current, average and 3740.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 insulated wire lead and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: